

# Ultra-Low-Level Optical Signal Detection and Signal Conditioning

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**Abstract - In applications such as precision sensing, spectroscopy, and biomedical instrumentation, ultra-low-level optical signal detection is essential. Accurately converting microampere-level photodiode current into a steady and measurable voltage while reducing noise and preserving linearity is the main difficulty in such systems.**

**.Keywords:- Photodiode, TIA, optical sensing, low-noise circuits, signal conditioning.**

## 1. INTRODUCTION

In order to detect ultra-low-level optical signals, very tiny photodiode currents must be precisely converted into detectable voltage signals while preserving linearity and stability. The proposed work uses a high-speed operational amplifier with a variable feedback network to dynamically control gain in order to implement a practical transimpedance amplifier (TIA). To simulate photodiode behavior, a controlled current source with a range of 0.5  $\mu\text{A}$  to 10  $\mu\text{A}$  is applied, and the resulting output voltage variations are examined. The circuit is appropriate for experimental validation of microampere-level optical detection systems because it places an emphasis on stable signal conditioning, low noise performance, and adjustable sensitivity.

## 2. CIRCUIT DESCRIPTION AND WORKING PRINCIPLE

The designed circuit corresponds to an actual realization of an operational amplifier

**This work uses a high-speed operational amplifier to implement a transimpedance amplifier (TIA) architecture to detect input currents between 0.5  $\mu\text{A}$  and 10  $\mu\text{A}$ . A variable potentiometer is incorporated into the feedback network to enable dynamic sensitivity tuning and adjustable gain control.**

transimpedance amplifier (TIA) circuit, which is used for ultra-low level optical signals. In this case, the photodiode is represented as a controlled current source, denoted as I1. This component injects a small level of current, in the range of microamperes, into the inverting input of the operational amplifier, denoted as U1. This model of the photodiode corresponds to an

actual realization of the standard model of the photodiode, where it is considered as a current source proportional to the level of the optical power [1], [9]

The operational amplifier is used as a transimpedance amplifier. As explained in Graeme [12] and Sackinger [4], the output voltage of the transimpedance amplifier is proportional to the level of the input current as well as the level of the resistance, shown as :  $V_{out} = -I_{in} R_f$

In this circuit, a variable resistor is incorporated in the feedback path, which makes it possible to vary the gain of the circuit. By changing the value of variable resistor R1 (1000 k $\Omega$  potentiometer), it is possible to vary the transimpedance gain to suit different input current ranges (0.5  $\mu\text{A}$  to 10  $\mu\text{A}$ ). This is necessary in real-world optical systems, as the intensity of light varies greatly [6].

The low values of the series resistors R3 and PR5 ensure stability in the input circuit. The use of the capacitor C2 in the circuit serves for supply decoupling. This is crucial in low current measurements [5], [11]. At the output end of the circuit, the capacitor C1 serves as a filter. It filters the output before it can be viewed using the oscilloscope.

## 3. SELECTION OF MULTISIM FOR CIRCUIT SIMULATION

For the analysis and validation of the proposed transimpedance amplifier (TIA), NI Multisim was chosen as the simulation environment. The reason behind choosing Multisim is its analog simulation engine that uses SPICE, which is reliable for simulating low current and high-gain amplifier circuits. Since the designed system is working at the microampere range of 0.5  $\mu\text{A}$  to 10  $\mu\text{A}$ , it is very crucial to accurately represent its current-voltage conversion stability.

Multisim allows real-time observation of the output voltage with the help of virtual oscilloscopes, which makes it easier to verify the proposed TIA relationship

$V_{out} = -I_{in}R_f$  as proposed by Graeme [12] and Sackinger [4]. It also allows detailed op-amp modeling, which makes it possible to analyze bandwidth and noise-related parameters of the

designed system with respect to real-world design considerations proposed by Razavi [6].

#### 4. PHOTODIODE REPRESENTATION IN MULTISIM

Once the platform for the simulations was identified as NI Multisim, the next step was to simulate the optical sensor element. In a practical scenario, a photodiode under reverse bias generates a current proportional to the incident optical power rather than a voltage output. This current-mode characteristic of a photodiode is well established in the theory of photodetectors [1], [9]. Hence, for circuit-level validation purposes, a photodiode can be well approximated as a current source.

In the current simulation scenario, an ideal DC current source was chosen as a substitute for the photodiode. The current was varied over a range of 0.5  $\mu\text{A}$  to 10  $\mu\text{A}$ . According to the principles of analysis of a transimpedance amplifier [4], validation of the current-to-voltage conversion characteristic using a controlled current source facilitates independent analysis of the performance of the amplifier.

#### 5. SIMULATION RESULTS AND CONTROLLED CURRENT VARIATION

In order to test and validate the performance of the proposed TIA with respect to its current-to-voltage conversion characteristics, the input current source has been varied step by step using NI Multisim. Figure 1(a), Figure 1(b), and Figure 1(c) illustrate the simulated response at the node when the input current source varies from 0.5  $\mu\text{A}$  to 10  $\mu\text{A}$ .

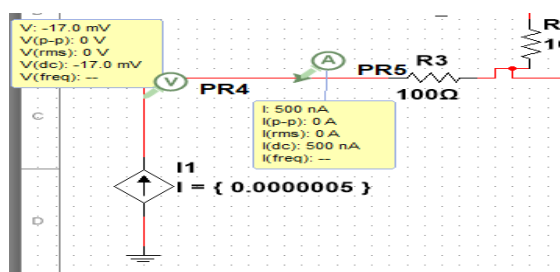


Figure 1(a)

In Figure 1(a), it can be observed that when the input current is set at 0.5  $\mu\text{A}$ , there is a change in the magnitude of voltage at the input node. This validates that the proposed amplifier can detect current variations at a sub-microampere level.

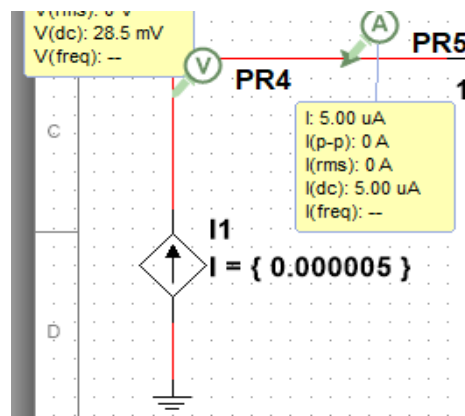


Figure 1(b)

In Figure 1(b), it can be observed that when the input current is set at 5  $\mu\text{A}$ , there is a corresponding change in the voltage magnitude. In Figure 1(c), it can be observed that when the input current is set at 10  $\mu\text{A}$ , there is a corresponding change in the voltage magnitude.

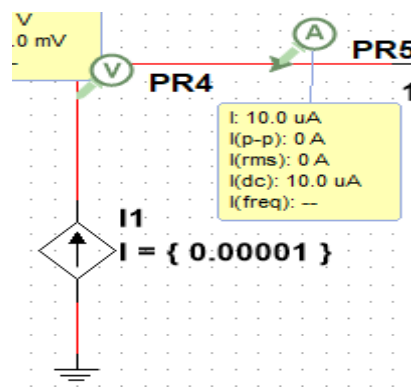


Figure 1(c)

From the results, it is confirmed that proportionality is achieved for the proposed configuration with respect to changes in the applied current.

#### 6. SELECTION OF OPA651U FOR ULTRA-LOW-LEVEL TIA APPLICATION

For the proposed transimpedance amplifier, the OPA651U device is chosen because it is best suited for high-speed and low-noise current-to-voltage conversion. In ultra-low-level optical detection, it is of prime importance that the operational amplifier has low input bias current, high bandwidth, and stability when operated at high gain. The OPA651U device has these characteristics, which make it best suited for microampere signal conditioning.

One of the major reasons for choosing this device is that it has a high bandwidth, which ensures that bandwidth is maintained when high feedback resistance is used. As discussed in transimpedance amplifier design literature [4], increasing feedback

resistance is desirable for increasing sensitivity but reduces bandwidth. A high-speed amplifier is needed to maintain bandwidth.

Furthermore, it has low input voltage noise, which is important for precision optical measurement systems where resistor thermal noise and amplifier noise can become predominant at high gain levels [7], [11]. The low bias current ensures that there is no error in current mode sensing, thus maintaining linearity as discussed under classical TIA analysis [12].

It can thus be concluded that OPA651U offers an effective solution for ultra-low-level optical signal sensing.

## 7. CIRCUIT DESCRIPTION

Figure 2 demonstrates the complete transimpedance amplifier circuit design intended for ultra-low-level optical signal detection. As indicated, the circuit design was constructed using the OPA651U component, with an inverting current-to-voltage conversion topology.

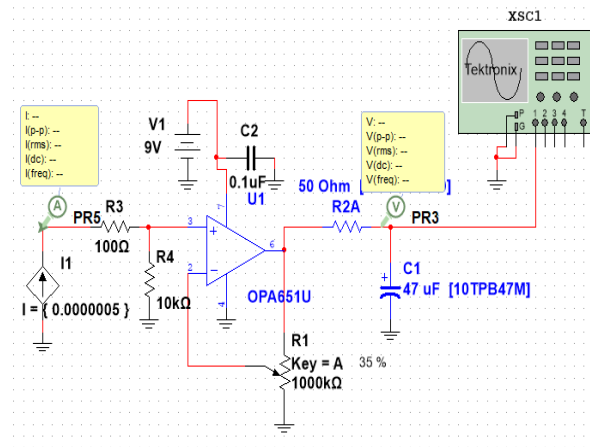


Figure 2

- Photodiode Modeling Using Current Source (I1)
- Input Stabilization Resistor (R3 – 100 Ω)
- Operational Amplifier Configuration (U1 – OPA651U)
- Feedback Network (R1 – 1 MΩ Potentiometer)
- Power Supply and Decoupling (V1 and C2 – 0.1 μF)
- Output Isolation and Filtering (R2A – 50 Ω and C1 – 47 μF)
- Measurement Using Oscilloscope

## 8. APPLICATIONS

In situations where the received optical power is very low and traditional detection methods are insufficient, ultra-low-level optical signal detection devices are essential. These systems are widely employed in fiber-optic sensing and communication, especially in distributed and long-distance sensing applications where signal attenuation is substantial. Ultra-low-level detection

is crucial for biomedical instrumentation methods such as optical biosensing, low-light imaging, and fluorescence-based diagnostics. Furthermore, highly sensitive photodiode-TIA front-end circuits are necessary for optical spectroscopy and astronomical apparatus to precisely measure weak light signals. In order to maintain signal integrity at very low signal levels, emerging fields like quantum optics and photon-counting systems further require ultra-low-noise current-to-voltage conversion.

## 9. RESEARCH GAP AND MOTIVATION

The majority of current designs are created for fixed gain operation and tailored for particular signal levels, despite the fact that a significant amount of research has been published on photodiode-based optical signal detection employing transimpedance amplifiers. Fixed-gain TIA systems are less flexible in real-world experimental and sensing settings since optical signal intensity can vary greatly. The need for straightforward and adaptable gain control in ultra-low-level signal situations is frequently overlooked in favor of either high sensitivity or broad bandwidth in many published solutions.

Additionally, although integrated TIA solutions have been extensively researched, nothing is known about workable, affordable Op-amp-based TIA designs that enable manual gain tweaking without sacrificing linearity, stability, or noise performance. Specifically, the research has not sufficiently examined the impact of adding adjustable feedback components, like potentiometers, in ultra-low-current photodiode signal conditioning circuits. This lack of focus highlights a clear research gap in developing a flexible and experimentally adaptable TIA-based signal conditioning approach suitable for ultra-low-level optical signal detection.

## 10. FUTURE SCOPE

The creation of highly integrated, low-noise TIA systems with enhanced thermal and long-term stability is anticipated to be the main focus of future developments in ultra-low-level optical signal detection. Adopting auto-ranging or digitally controlled gain mechanisms can increase system flexibility while lowering the need for manual calibration. Advanced noise-reduction strategies, such as bandwidth management, hybrid analog-digital signal processing, and optimal feedback network design, may yield even greater gains. It is expected that the combination of intelligent calibration algorithms and digital signal processing (DSP) will enhance sensitivity, resilience, and flexibility under various operating situations. Next-generation optical detecting systems with improved performance for industrial, scientific, and medical applications will be made possible by these developments.

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